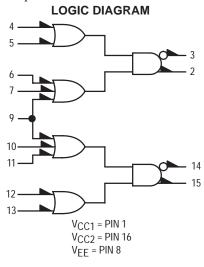
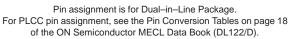
Dual 2-Wide 2-3-Input OR-AND/OR-AND Gate

The MC10H117 dual 2-wide 2-3-input OR-AND/ OR-AND-Invert gate is a general purpose logic element designed for use in data control, such as digital multiplexing or data distribution. Pin 9 is common to both gates. This MECL 10H part is a functional/pinout duplication of the standard MECL 10K family part, with 100% improvement in propagation delay, and no increase in power-supply current.

- Propagation Delay, 1.0 ns Typical
- Power Dissipation 100 mW/Gate Typical (same as MECL 10K)
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- Voltage Compensated
- MECL 10K–Compatible



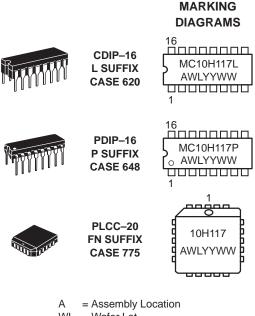






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WL = Wafer Lot YY = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping		
MC10H117L	CDIP-16	25 Units/Rail		
MC10H117P	PDIP-16	25 Units/Rail		
MC10H117FN	PLCC-20	46 Units/Rail		

MAXIMUM RATINGS

Symbol	Characteristic	Rating	Unit
VEE	Power Supply ($V_{CC} = 0$)	-8.0 to 0	Vdc
VI	Input Voltage ($V_{CC} = 0$)	0 to V _{EE}	Vdc
l _{out}	Output Current — Continuous — Surge	50 100	mA
TA	Operating Temperature Range	0 to +75	°C
T _{stg}	Storage Temperature Range — Plastic — Ceramic	−55 to +150 −55 to +165	°C ℃

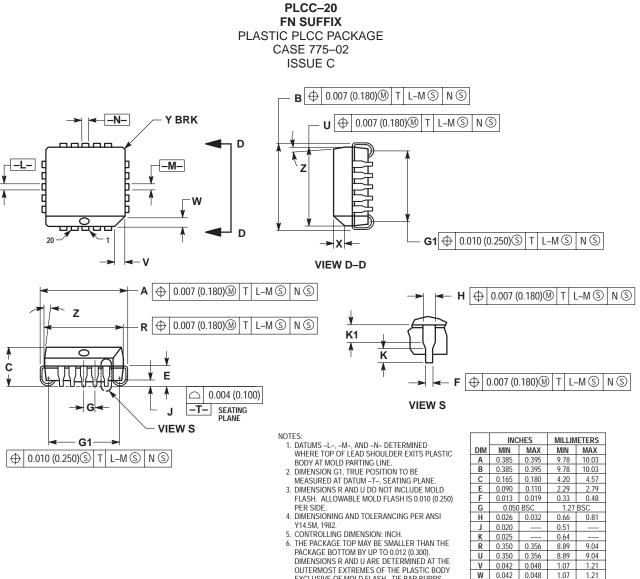
ELECTRICAL CHARACTERISTICS (V_{EE} = $-5.2 \text{ V} \pm 5\%$) (See Note 1.)

		0 ° 25 °		5°	75°			
Symbol	Characteristic	Min	Max	Min	Max	Min	Max	Unit
١E	Power Supply Current	—	29	—	26	—	29	mA
linH	Input Current High Pins 4, 5, 12, 13 Pins 6, 7, 10, 11 Pin 9	 	465 545 710		275 320 415		275 320 415	μA
l _{inL}	Input Current Low	0.5	—	0.5	—	0.3	—	μΑ
Vон	High Output Voltage	-1.02	-0.84	-0.98	-0.81	-0.92	-0.735	Vdc
VOL	Low Output Voltage	-1.95	-1.63	-1.95	-1.63	-1.95	-1.60	Vdc
VIH	High Input Voltage	-1.17	-0.84	-1.13	-0.81	-1.07	-0.735	Vdc
VIL	Low Input Voltage	-1.95	-1.48	-1.95	-1.48	-1.95	-1.45	Vdc
AC PARAM	AC PARAMETERS							

t _{pd} Propagation Delay		0.45	1.35	0.45	1.35	0.5	1.5	ns
tr	Rise Time	0.5	1.5	0.5	1.6	0.5	1.7	ns
t _f	Fall Time	0.5	1.5	0.5	1.6	0.5	1.7	ns

 Each MECL 10H series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to -2.0 volts.

PACKAGE DIMENSIONS



DIMENSIONS R AND UARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY. 7. DIMENSION H DOES NOT INCLUDE DAMBAR

1.42

0.50

10 °

8.38

1.07

7.88

1.02

X 0.042 Y ----

K1 0.040

2° 10°

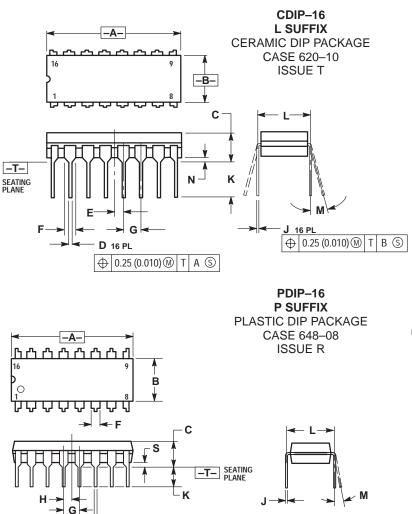
G1 0.310 0.330

Ζ

0.056

0.020

AND BOTTOM OF THE PLASTIC BODT. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEAD WHEN 3
- FORMED PARALLEL. DIMENSION F MAY NARROW TO 0.76 (0.030)

4 WHERE THE LEAD ENTERS THE CERAMIC BODY

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.015 0.020		0.50	
Ε	0.050 BSC		1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100 BSC		2.54 BSC		
Н	0.008	0.015	0.21	0.38	
К	0.125	0.170	3.18	4.31	
L	0.300 BSC		7.62 BSC		
Μ	0 °	15°	0 °	15 °	
Ν	0.020	0.040	0.51	1.01	

NOTES

- DIMENSIONING AND TOLERANCING PER ANSI 1
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH. ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIN	IETERS		
DIM	MIN	MAX	MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
С	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100 BSC		2.54 BSC			
Н	0.050	0.050 BSC		1.27 BSC		
J	0.008	0.015	0.21	0.38		
К	0.110	0.130	2.80	3.30		
L	0.295	0.305	7.50	7.74		
М	0°	10 °	0 °	10 °		
S	0.020	0.040	0.51	1.01		

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